TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK2035

High Speed Switching Applications Analog Switching Applications

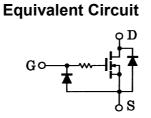
- High input impedance.
- Low gate threshold voltage: $V_{th} = 0.5 \sim 1.5 \text{ V}$
- Excellent switching times: $t_{on} = 0.16 \ \mu s \ (typ.)$

t_{off} = 0.15 μs (typ.)

- Small package
- Enhancement-mode

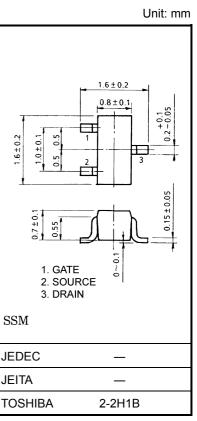
Marking





Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DS}	20	V
Gate-source voltage	V _{GSS}	10	V
Drain current	Ι _D	100	mA
Drain power dissipation	PD	100	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C



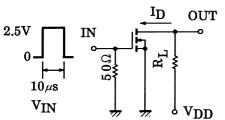
Weight: 2.4 mg (typ.)

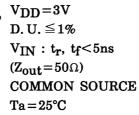
Note: This transistor is electrostatic sensitive device. Please handle with caushon.

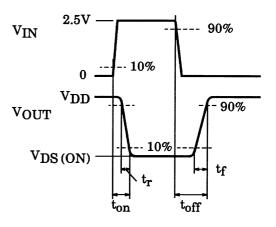
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=10~V,~V_{DS}=0$	_	_	1	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 100 \ \mu A, \ V_{GS} = 0$	20	_	_	V
Drain cut-off curre	ent	I _{DSS}	$V_{DS}=20~V,~V_{GS}=0$	_	—	1	μA
Gate threshold vo	Itage	V _{th}	$V_{DS} = 3 V, I_D = 0.1 mA$	0.5	_	1.5	V
Forward transfer a	admittance	Y _{fs}	$V_{DS} = 3 V, I_D = 10 mA$	25	50	_	mS
Drain-source ON resistance		R _{DS (ON)}	$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$	_	8	12	Ω
Input capacitance		C _{iss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$	_	8.5	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$	_	3.3	_	pF
Output capacitance		C _{oss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$	_	9.3	_	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 \text{ V}, \text{ I}_{D} = 10 \text{ mA}, \text{ V}_{GS} = 0 \sim 2.5 \text{ V}$	_	0.16	_	μS
	Turn-off time	t _{off}	$V_{DD} = 3 \text{ V}, \text{ I}_{D} = 10 \text{ mA}, \text{ V}_{GS} = 0 2.5 \text{ V}$	_	0.15	_	

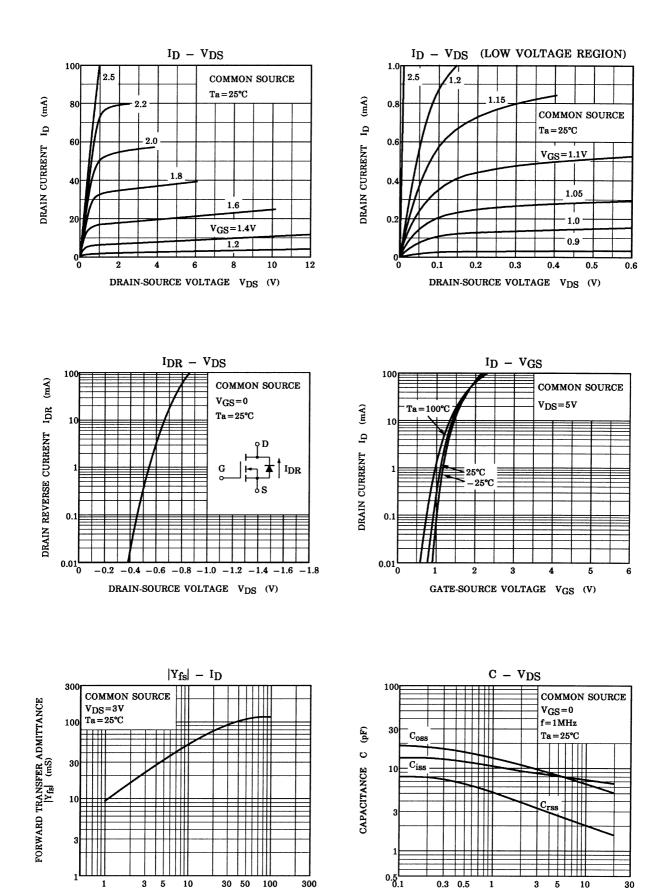
Switching Time Test Circuit







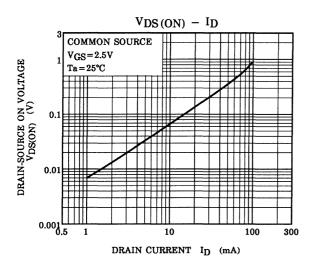
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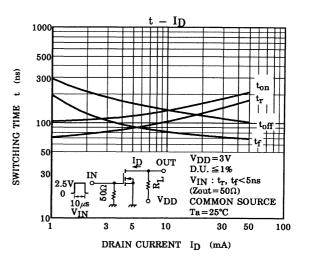


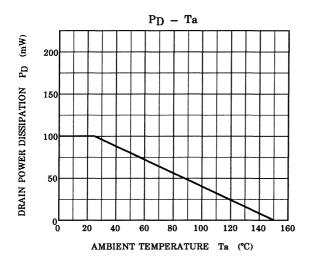
DRAIN-SOURCE VOLTAGE V_{DS} (V)

DRAIN CURRENT ID (mA)

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